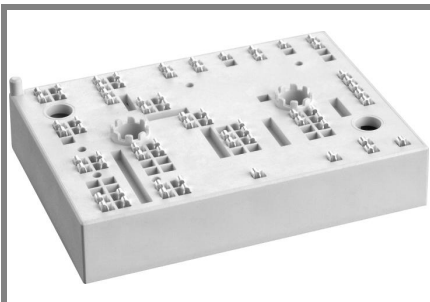


SKiiP 37AC12T4V1



MiniSKiiP® 3

3-phase bridge inverter

SKiiP 37AC12T4V1

Features

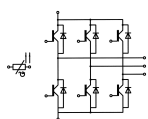
- Trench 4 IGBT's
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications*

- Inverter up to 36 kVA
- Typical motor power 22 kW

Remarks

- V_{CEsat} , V_F = chip level value
- Case temp. limited to $T_C = 125^\circ\text{C}$ max. (for baseplateless modules $T_C = T_S$)
- product rel. results valid for $T_j \leq 150$ (recomm. $T_{op} = -40 \dots +150^\circ\text{C}$)

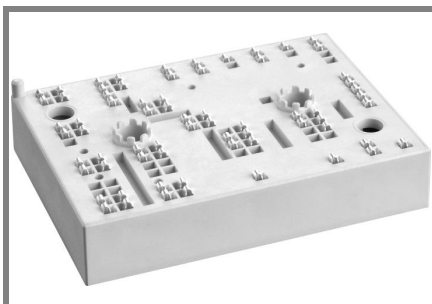


AC

Absolute Maximum Ratings		$T_S = 25^\circ\text{C}$, unless otherwise specified		
Symbol	Conditions	Values		Units
IGBT				
V_{CES}	$T_j = 25^\circ\text{C}$	1200		V
I_C	$T_j = 175^\circ\text{C}$	$T_c = 25^\circ\text{C}$	90	A
		$T_c = 70^\circ\text{C}$	73	A
I_{CRM}	$I_{CRM} = 3 \times I_{Cnom}$	225		A
V_{GES}		± 20		V
t_{psc}	$V_{CC} = 800\text{ V}; V_{GE} \leq 15\text{ V}; T_j = 150^\circ\text{C}$ $V_{CES} < 1200\text{ V}$	10		μs
Inverse Diode				
I_F	$T_j = 175^\circ\text{C}$	$T_c = 25^\circ\text{C}$	82	A
		$T_c = 70^\circ\text{C}$	66	A
I_{FRM}	$I_{CRM} = 3 \times I_{Cnom}$	225		A
I_{FSM}	$t_p = 10\text{ ms}; \sin$	$T_j = 150^\circ\text{C}$	425	A
Module				
$I_{t(RMS)}$		160		A
T_{vj}		-40...+150		$^\circ\text{C}$
T_{stg}		-40...+125		$^\circ\text{C}$
V_{isol}	AC, 1 min.	2500		V

Characteristics		$T_S = 25^\circ\text{C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT					
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 3\text{ mA}$	5	5,8	6,5	V
I_{CES}	$V_{GE} = V, V_{CE} = V_{CES}$	$T_j = 25^\circ\text{C}$			mA
		$T_j = 150^\circ\text{C}$	0,8	0,9	V
V_{CE0}			0,7	0,8	V
r_{CE}	$V_{GE} = 15\text{ V}$	$T_j = 25^\circ\text{C}$	14	15	$\text{m}\Omega$
		$T_j = 150^\circ\text{C}$	21	22	$\text{m}\Omega$
$V_{CE(sat)}$	$I_{Cnom} = 75\text{ A}, V_{GE} = 15\text{ V}$	$T_j = 25^\circ\text{C}_{chiplev.}$	1,85	2,05	V
		$T_j = 150^\circ\text{C}_{chiplev.}$	2,25	2,45	V
C_{ies}	$V_{CE} = 25, V_{GE} = 0\text{ V}$	$f = 1\text{ MHz}$	4,4		nF
C_{oes}			0,29		nF
C_{res}			0,24		nF
Q_G	$V_{GE} = -8..+15\text{V}$		425		nC
R_{Gint}	$T_j = 25^\circ\text{C}$		10		Ω
$t_{d(on)}$	$R_{Gon} = 1\ \Omega$ $di/dt = 1560\text{ A}/\mu\text{s}$	$V_{CC} = 600\text{V}$ $I_C = 75\text{A}$	145		ns
t_r			45		ns
E_{on}	$R_{Goff} = 1\ \Omega$ $di/dt = 1180\text{ A}/\mu\text{s}$	$T_j = 150^\circ\text{C}$ $V_{GE} = \pm 15\text{V}$	11,5		mJ
$t_{d(off)}$			350		ns
t_f			65		ns
E_{off}			6,8		mJ
$R_{th(j-s)}$	per IGBT		0,58		K/W

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Features

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Typical Applications*

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- Typical motor power 22 kW

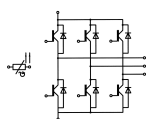
Remarks

- V_{CEsat} , V_F = chip level value
- Case temp. limited to $T_C = 125^\circ\text{C}$ max. (for baseplateless modules $T_C = T_S$)
- product rel. results valid for $T_j \leq 150$ (recomm. $T_{op} = -40 \dots +150^\circ\text{C}$)

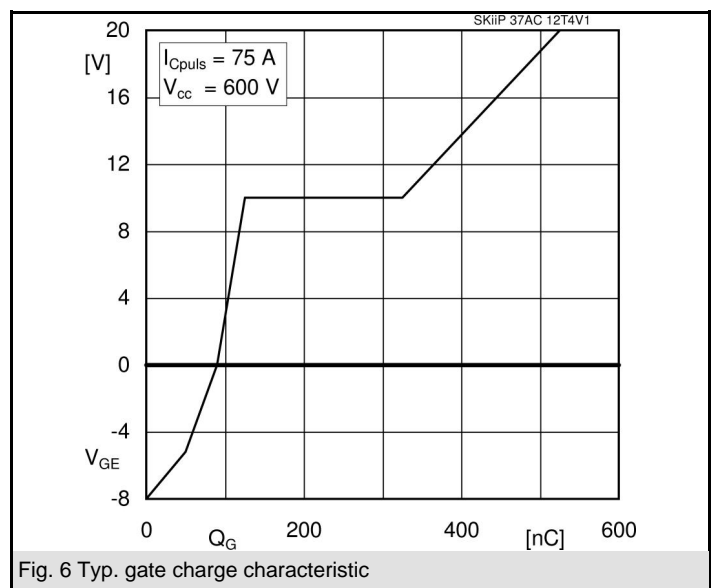
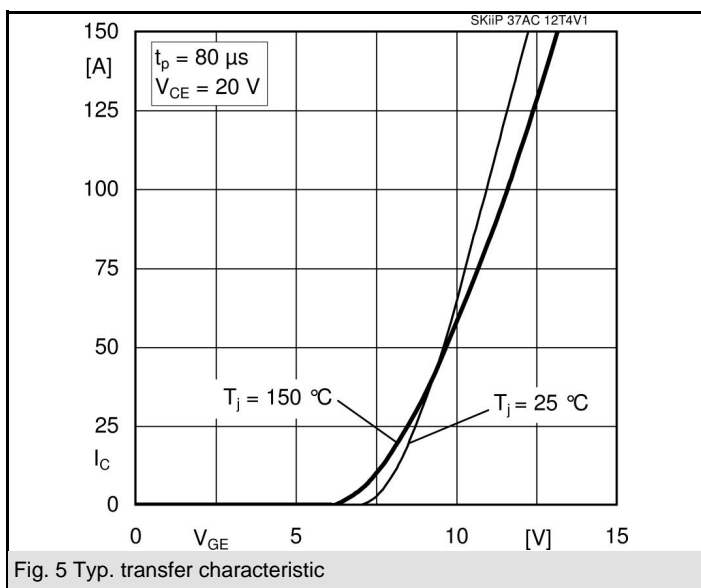
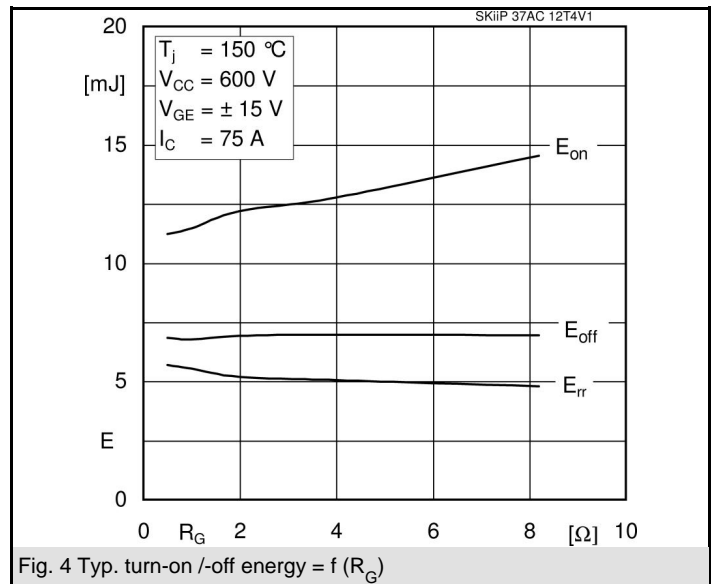
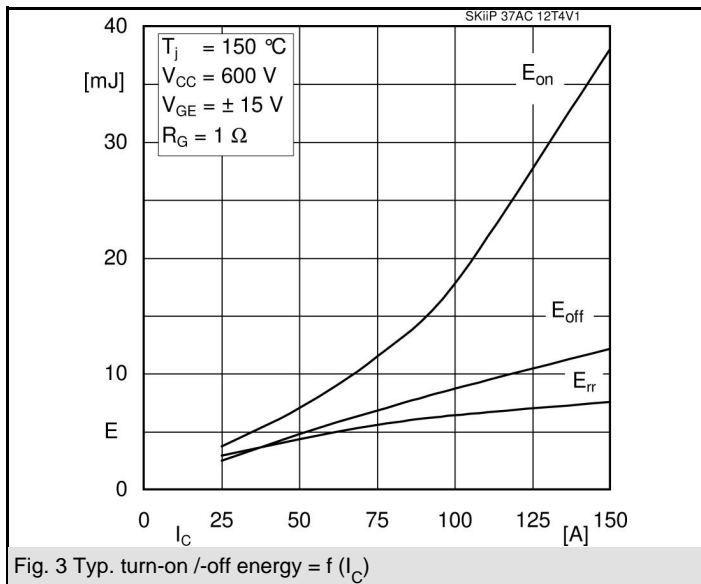
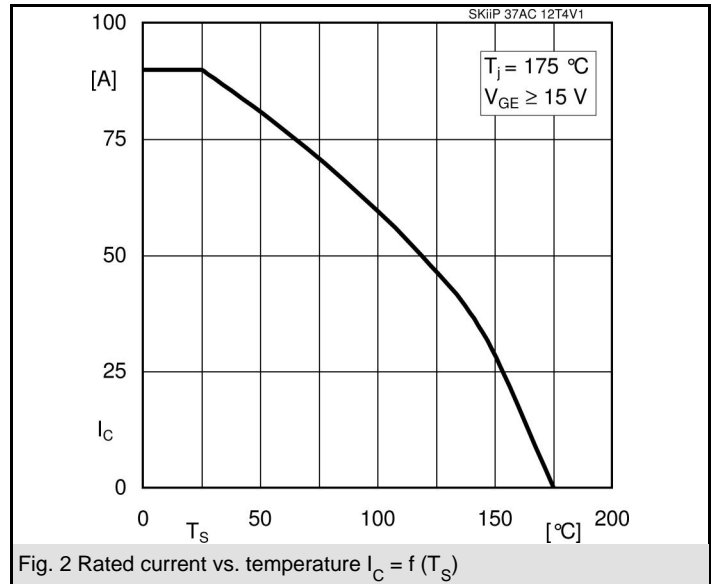
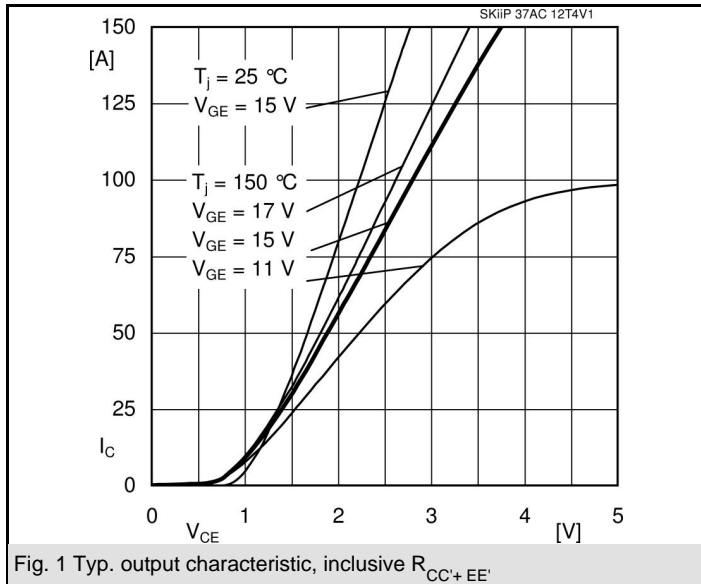
Characteristics				min.	typ.	max.	Units
Symbol	Conditions						
Inverse Diode							
$V_F = V_{EC}$	$I_{Fnom} = 75 \text{ A}; V_{GE} = 15 \text{ V}$	$T_j = 25^\circ\text{C}_{chiplev.}$		2,2	2,5		V
		$T_j = 150^\circ\text{C}_{chiplev.}$		2,1	2,45		V
V_{F0}		$T_j = 25^\circ\text{C}$		1,3	1,5		V
		$T_j = 150^\circ\text{C}$		0,9	1,1		V
r_F		$T_j = 25^\circ\text{C}$		12	13		mΩ
		$T_j = 150^\circ\text{C}$		16	18		mΩ
I_{RRM}	$I_F = 75 \text{ A}$	$T_j = 150^\circ\text{C}$		99			A
Q_{rr}	$di/dt = 2440 \text{ A}/\mu\text{s}$			13,3			μC
E_{rr}	$V_{GE} = \pm 15 \text{ V}$			5,5			mJ
$R_{th(j-s)}$	per diode			0,75			K/W
M_s	to heat sink			2	2,5		Nm
w				95			g
Temperature sensor							
R_{ts}	3%, $T_r = 25^\circ\text{C}$			1000			Ω
R_{ts}	3%, $T_r = 100^\circ\text{C}$			1670			Ω

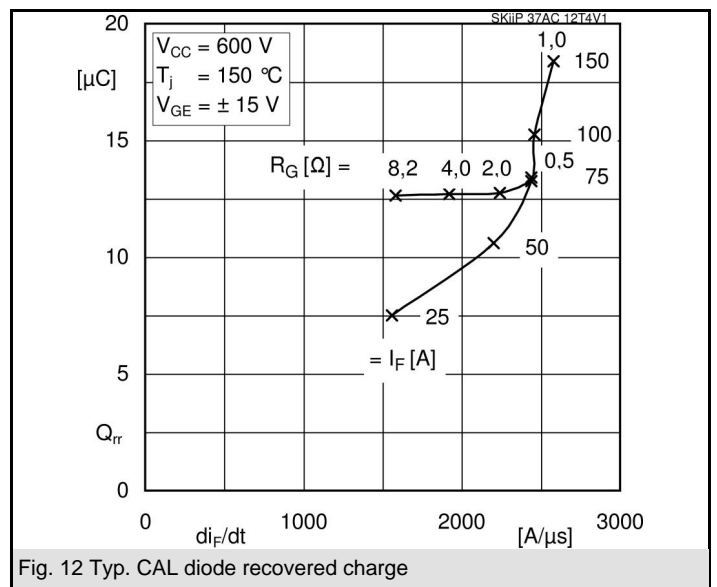
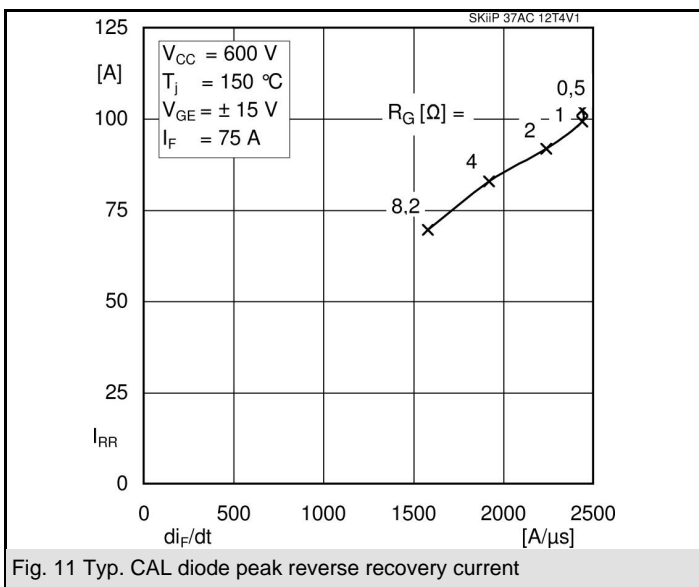
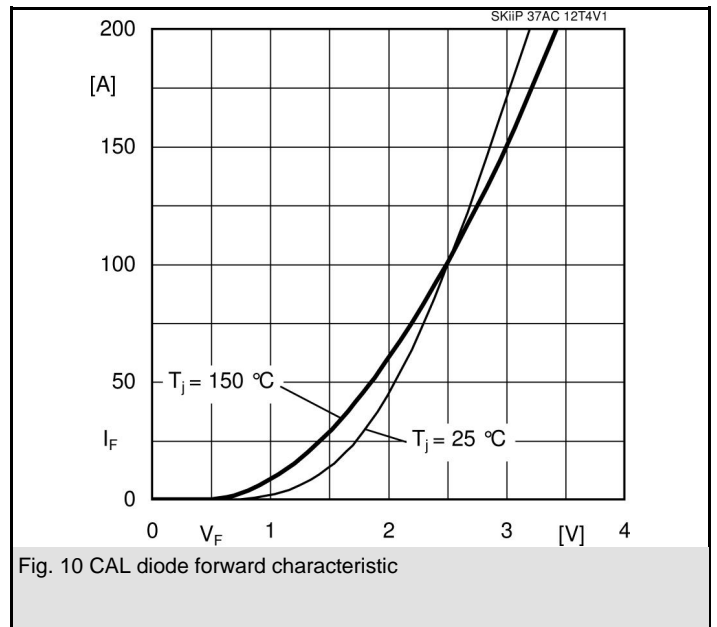
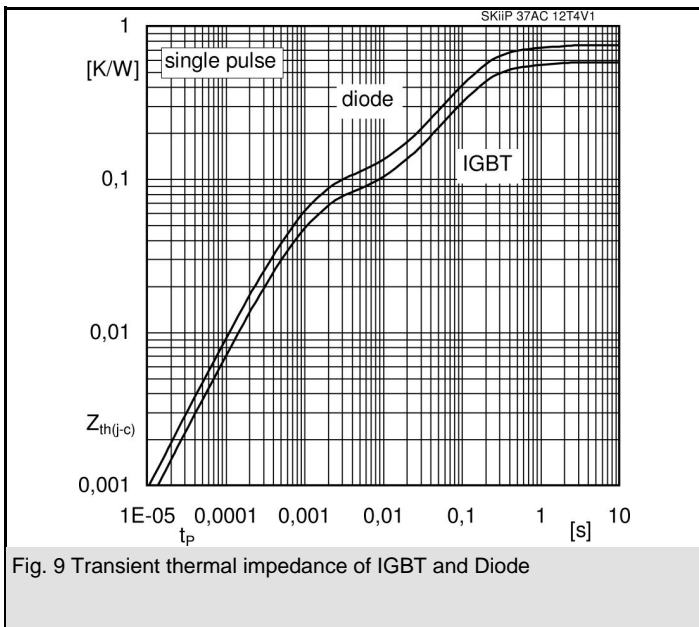
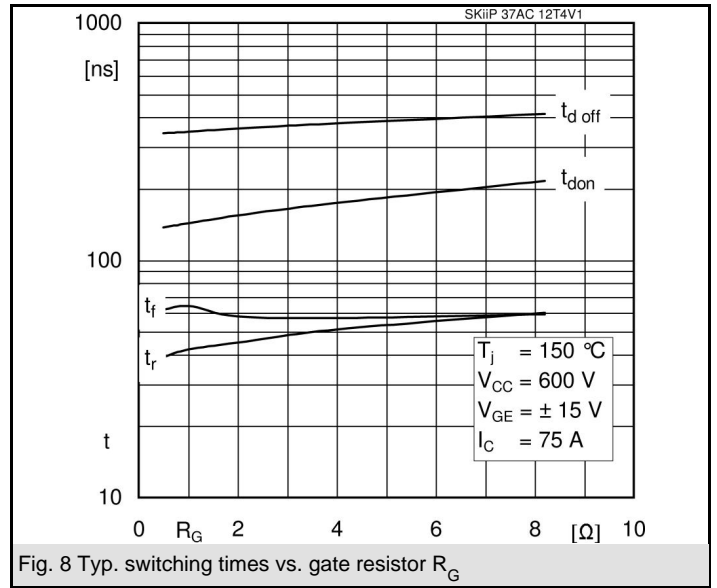
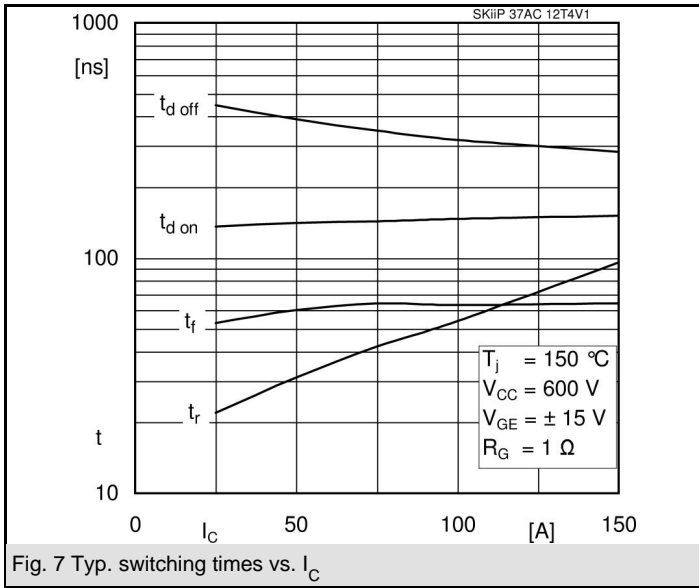
This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.



AC

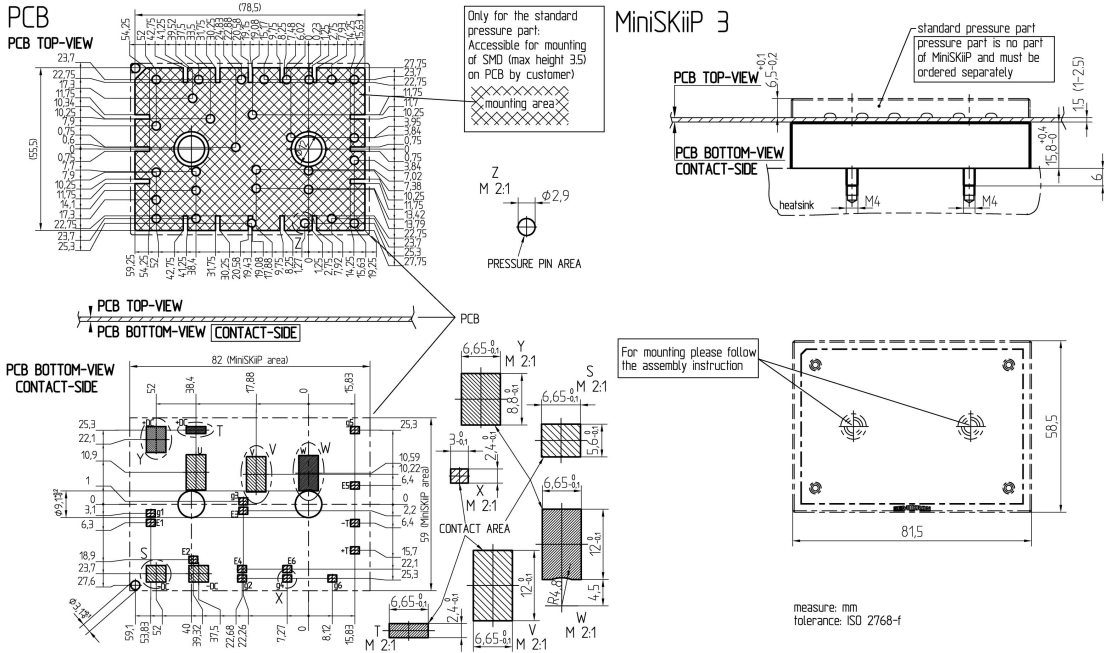




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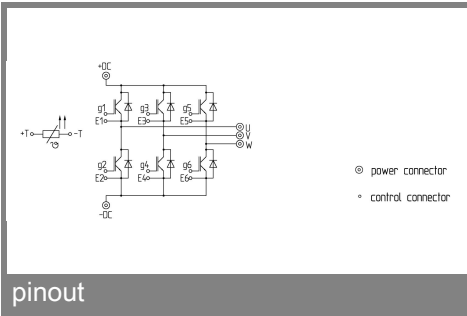
UL recognized file

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case



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